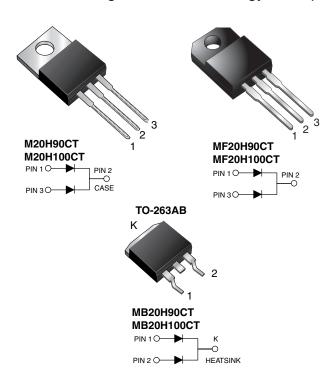


Vishay General Semiconductor

RoHS

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V_{RRM}	90 V to 100 V				
I _{FSM}	250 A				
I _R	4.5 μA				
V_{F}	0.64				
T _J max.	175 °C				
Package	TO-220AB, ITO-220AB, TO-263AB				
Diode variations	Dual common cathode				

FEATURES

- Power pack
- · Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3 A
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,.....)

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	M20H90CT	M20H100CT	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	90	100		
Working peak reverse voltage		V_{RWM}	90	100	V	
Maximum DC blocking voltage		V_{DC}	90	100	1	
Maximum average forward rectified current	total device	I	20			
	per diode	I _{F(AV)}	10			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	250		A	
Peak repetitive reverse current per diode at $t_p = 2.0 \mu s$, 1 kHz		I _{RRM}	1.0			
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs	
Operating junction and storage temperature range		T _J . T _{STG}	-65 to +175		°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500		V	



M20HxxCT, MB20HxxCT, MF20HxxCT

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V _F (1)	I _F = 10 A	T _C = 25 °C	0.77	- V	
		I _F = 10 A	T _C = 125 °C	0.64		
		I _F = 20 A	T _C = 25 °C	0.88		
		I _F = 20 A	T _C = 125 °C	0.73		
Maximum reverse current at working peak reverse voltage per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	4.5	μΑ	
			T _J = 125 °C	6.0	mA	

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	М	МВ	MF	UNIT
Typical thermal resistance per diode	$R_{ heta JC}$	2.0	2.0	5.8	°C/W

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	M20H100CTHE3_A/P (1)	1.85	Р	50/tube	Tube	
ITO-220AB	MF20H100CTHE3_A/P (1)	1.99	Р	50/tube	Tube	
TO-263AB	MB20H100CTHE3_A/P (1)	1.35	Р	50/tube	Tube	
TO-263AB	MB20H100CTHE3_A/I (1)	1.35	I	800/reel	Tape and reel	

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

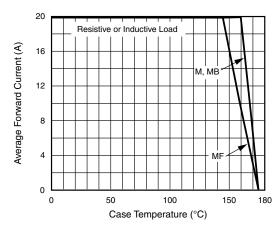


Fig. 1 - Forward Current Derating Curve

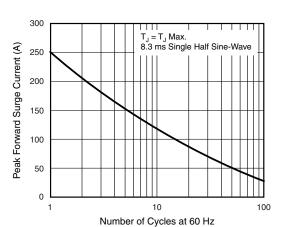


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

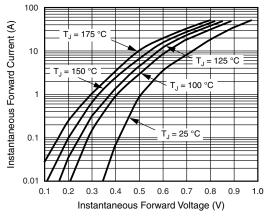


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

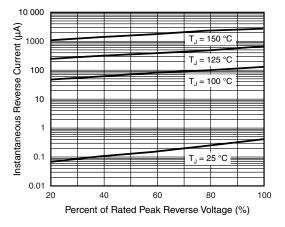


Fig. 4 - Typical Reverse Characteristics Per Diode

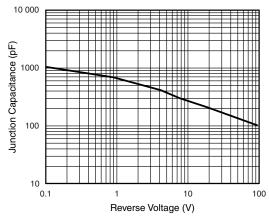


Fig. 5 - Typical Junction Capacitance Per Diode

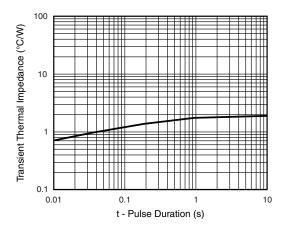


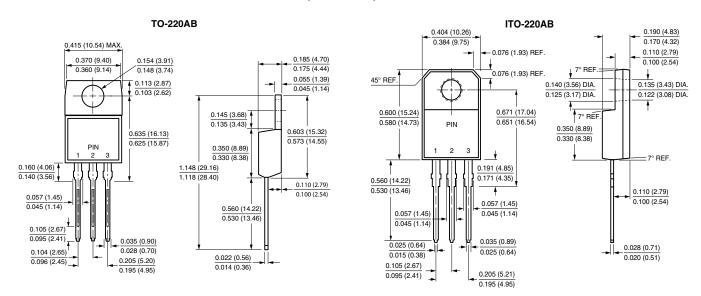
Fig. 6 - Typical Transient Thermal Impedance Per Diode

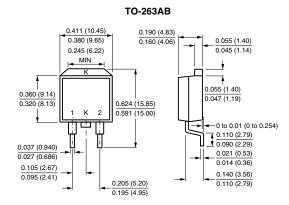


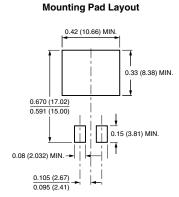
M20HxxCT, MB20HxxCT, MF20HxxCT

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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